Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material: Metal	
Overall Length:	
Between 0.190 inches and 0.205 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.210 inches and 0.225 inches	
Electrode Internally-electrically Connected	d To Case
Collector	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
Between 0.090 inches and 0.110 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic	
	open all transistor and 80.0 collector to emitter voltage/static/base open all transistor and 15
emitter to base voltage, static, collector ope	
Power Rating Per Characteristic:	
1.8 watts small-signal input power, common-	-collector preset all transistor
Maximum Operating Tempurature Per Mea	asurement Point:
125.0 degrees celsius ambient air	
Special Features:	
All transistor junction pattern arrangement: n	ipn
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	